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# ECH8652

## P-Channel Power MOSFET -12V, -6A, 28mΩ, Dual ECH8

ON Semiconductor®

<http://onsemi.com>

### Features

- Low ON-resistance
- 1.8V drive
- Composite type, facilitating high-density mounting
- Halogen free compliance
- Protection diode in

### Specifications

**Absolute Maximum Ratings** at Ta=25°C

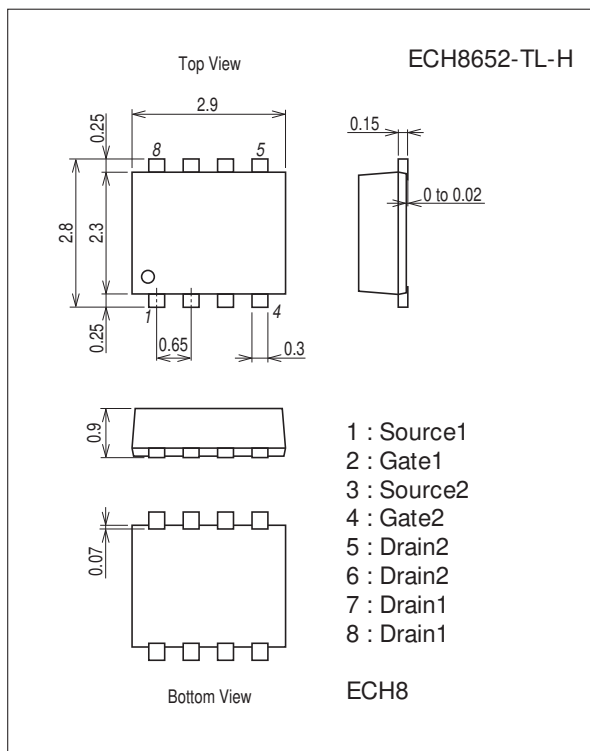
| Parameter                   | Symbol           | Conditions  | Ratings     | Unit |
|-----------------------------|------------------|---|-------------|------|
| Drain-to-Source Voltage     | V <sub>DSS</sub> |   | -12         | V    |
| Gate-to-Source Voltage      | V <sub>GSS</sub> |   | ±10         | V    |
| Drain Current (DC)          | I <sub>D</sub>   |   | -6          | A    |
| Drain Current (Pulse)       | I <sub>DP</sub>  | PW≤10μs, duty cycle≤1%  | -40         | A    |
| Allowable Power Dissipation | P <sub>D</sub>   | When mounted on ceramic substrate (900mm <sup>2</sup> ×0.8mm) 1unit | 1.3         | W    |
| Total Power Dissipation     | P <sub>T</sub>   | When mounted on ceramic substrate (900mm <sup>2</sup> ×0.8mm)       | 1.5         | W    |
| Channel Temperature         | T <sub>ch</sub>  |   | 150         | °C   |
| Storage Temperature         | T <sub>stg</sub> |   | -55 to +150 | °C   |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### Package Dimensions

unit : mm (typ)

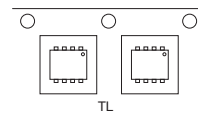
7011A-001



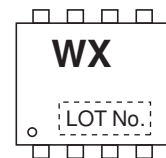
### Product & Package Information

- Package : ECH8
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

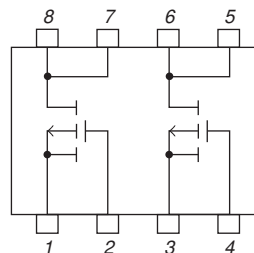
### Packing Type : TL



### Marking



### Electrical Connection

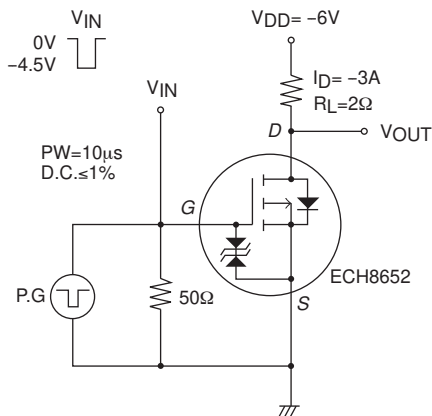


# ECH8652

## Electrical Characteristics at Ta=25°C

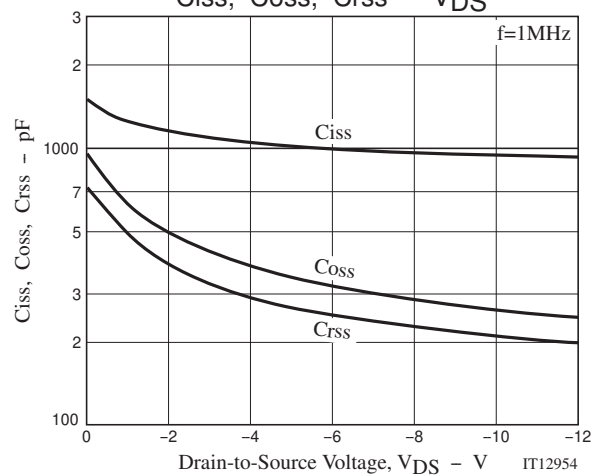
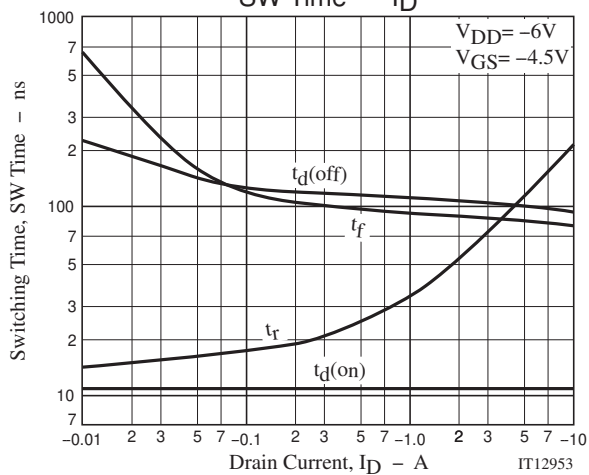
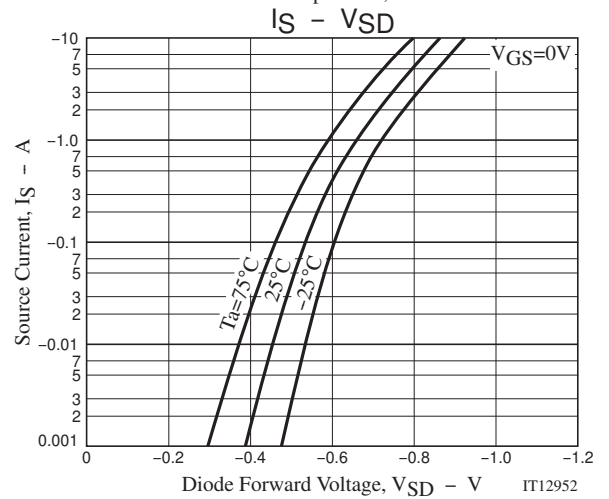
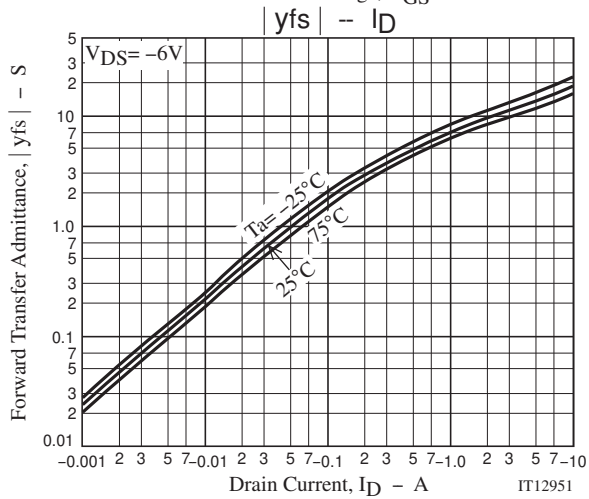
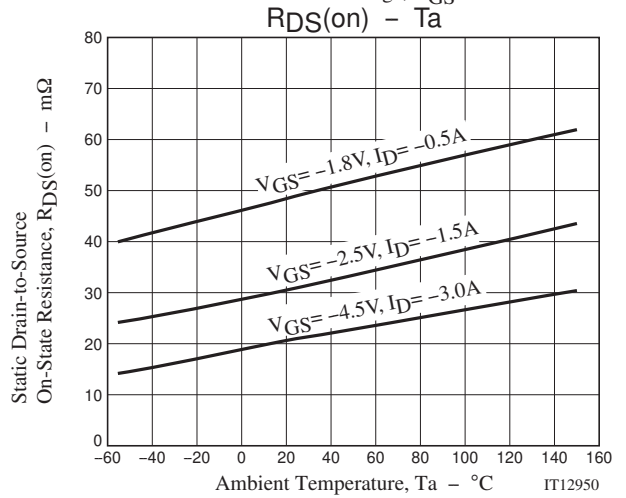
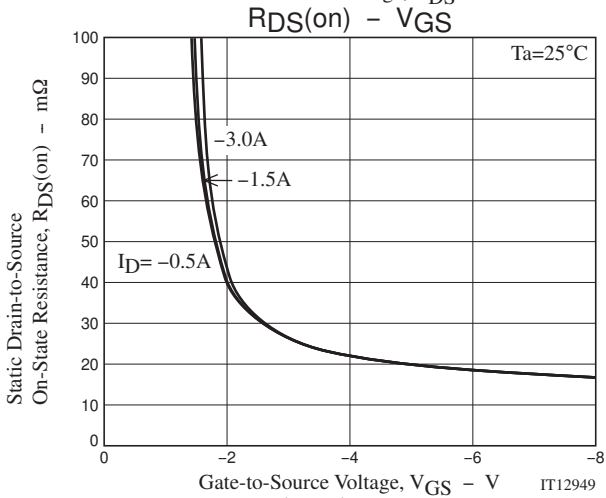
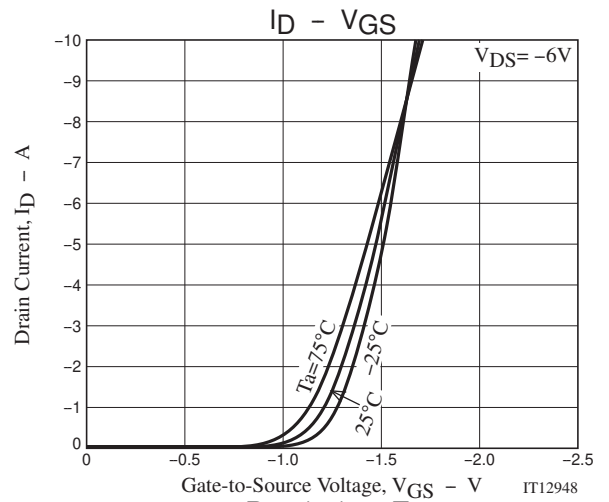
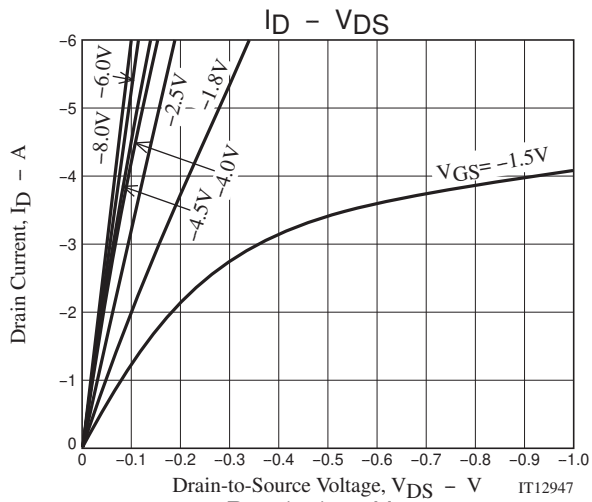
| Parameter                                  | Symbol        | Conditions   | Ratings                                |      |          | Unit             |
|--|---------------|--|--|------|----------|------------------|
|  |               |  | min                                    | typ  | max      |                  |
| Drain-to-Source Breakdown Voltage          | $V_{(BR)DSS}$ | $I_D = -1\text{mA}, V_{GS} = 0\text{V}$                        | -12                                    |      |          | V                |
| Zero-Gate Voltage Drain Current            | $I_{DSS1}$    | $V_{DS} = -8\text{V}, V_{GS} = 0\text{V}$                      |  |      | -1       | $\mu\text{A}$    |
|  | $I_{DSS2}$    | $V_{DS} = -12\text{V}, V_{GS} = 0\text{V}$                     |  |      | -10      | $\mu\text{A}$    |
| Gate-to-Source Leakage Current             | $I_{GSS}$     | $V_{GS} = \pm 8\text{V}, V_{DS} = 0\text{V}$                   |  |      | $\pm 10$ | $\mu\text{A}$    |
| Cutoff Voltage                             | $V_{GS(off)}$ | $V_{DS} = -6\text{V}, I_D = -1\text{mA}$                       | -0.4                                   |      | -1.4     | V                |
| Forward Transfer Admittance                | $ y_{fs} $    | $V_{DS} = -6\text{V}, I_D = -3\text{A}$                        | 6.6                                    | 11   |          | S                |
| Static Drain-to-Source On-State Resistance | $R_{DS(on)1}$ | $I_D = -3\text{A}, V_{GS} = -4.5\text{V}$                      |  | 21   | 28       | $\text{m}\Omega$ |
|  | $R_{DS(on)2}$ | $I_D = -1.5\text{A}, V_{GS} = -2.5\text{V}$                    |  | 31   | 45       | $\text{m}\Omega$ |
|  | $R_{DS(on)3}$ | $I_D = -0.5\text{A}, V_{GS} = -1.8\text{V}$                    |  | 49   | 78       | $\text{m}\Omega$ |
| Input Capacitance                          | $C_{iss}$     |  |  | 1000 |          | $\text{pF}$      |
| Output Capacitance                         | $C_{oss}$     | $V_{DS} = -6\text{V}, f = 1\text{MHz}$                         |  | 320  |          | $\text{pF}$      |
| Reverse Transfer Capacitance               | $C_{rss}$     |  |  | 250  |          | $\text{pF}$      |
| Turn-ON Delay Time                         | $t_d(on)$     | See specified Test Circuit.                                    |  | 11   |          | ns               |
| Rise Time                                  | $t_r$         |  |  | 72   |          | ns               |
| Turn-OFF Delay Time                        | $t_d(off)$    |  |  | 105  |          | ns               |
| Fall Time                                  | $t_f$         |  |  | 87   |          | ns               |
| Total Gate Charge                          | $Q_g$         |  |  |      | 11       |                  |
| Gate-to-Source Charge                      | $Q_{gs}$      | $V_{DS} = -6\text{V}, V_{GS} = -4.5\text{V}, I_D = -6\text{A}$ |  | 1.5  |          | nC               |
| Gate-to-Drain "Miller" Charge              | $Q_{gd}$      |  |  | 2.9  |          | nC               |
| Diode Forward Voltage                      | $V_{SD}$      |  | $I_S = -6\text{A}, V_{GS} = 0\text{V}$ |      | -0.81    | -1.2             |

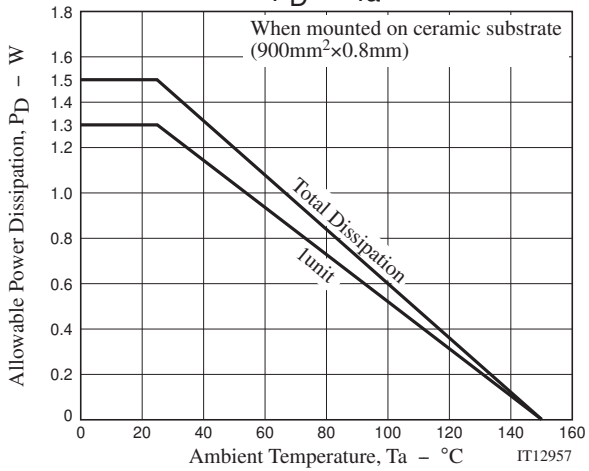
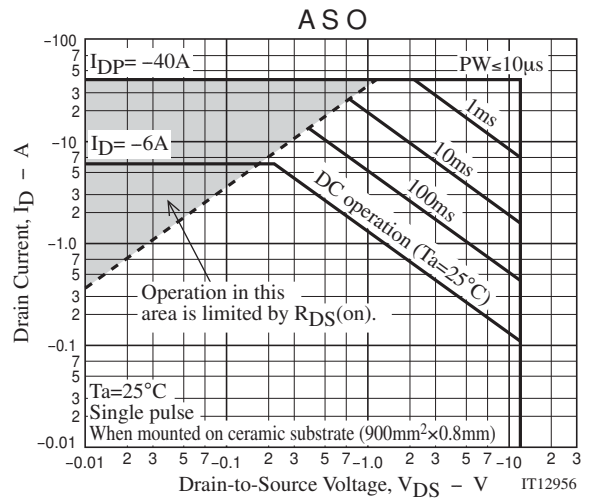
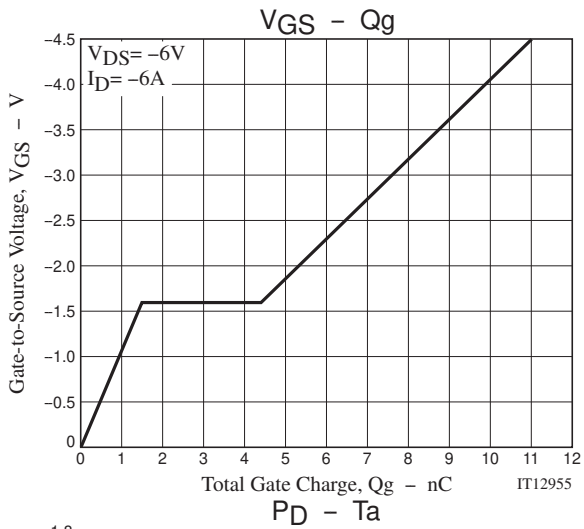
## Switching Time Test Circuit



## Ordering Information

| Device       | Package | Shipping       | memo                     |
|--------------|---------|----------------|--------------------------|
| ECH8652-TL-H | ECH8    | 3,000pcs./reel | Pb Free and Halogen Free |





Embossed Taping Specification

ECH8652-TL-H

1. Packing Format

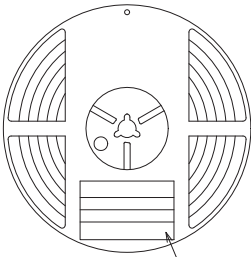
| Package Name | Carrier Tape Type | Maximum Number of devices contained (pcs) |           |           | Packing format  |  |
|--------------|-------------------|---|-----------|-----------|---|--|
|              |                   | Reel                                      | Inner box | Outer box | Inner BOX (C-1)   | Outer BOX (A-7)  |
| ECH8         | CPH6              | 3,000                                     | 15,000    | 90,000    | 5 reels contained<br>Dimensions:mm (external)<br>183×72×185 | 6 inner boxes contained<br>Dimensions:mm (external)<br>440×195×210 |

Reel label, Inner box label  
(unit :mm)

Outer box label

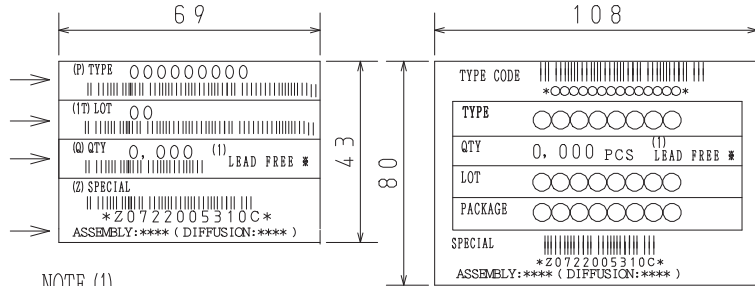
It is a label at the time of factory shipments.  
The form of a label may change in physical distribution process.

Packing method



Reel label

Type No.  
LOT No.  
Quantity  
Origin



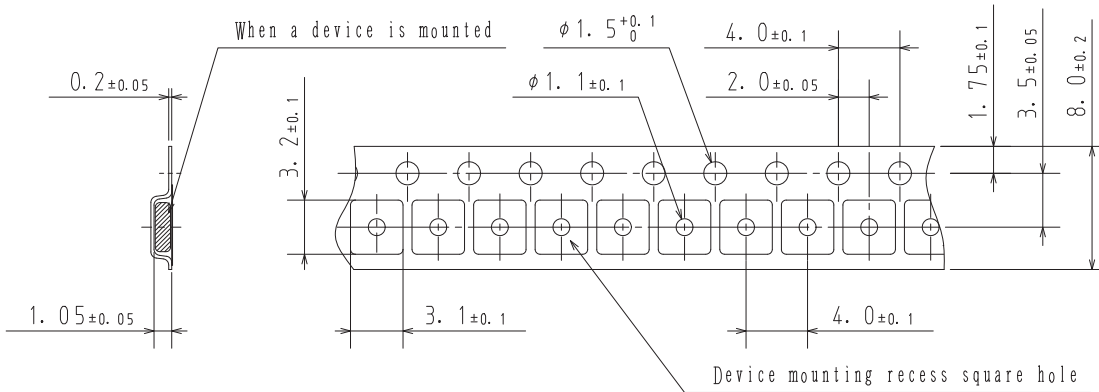
NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

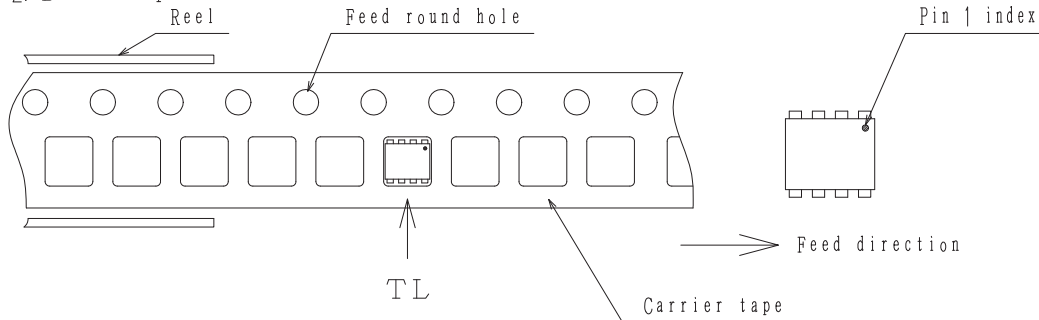
| Label       | JEITA Phase    |
|-------------|----------------|
| LEAD FREE 3 | JEITA Phase 3A |
| LEAD FREE 4 | JEITA Phase 3  |

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

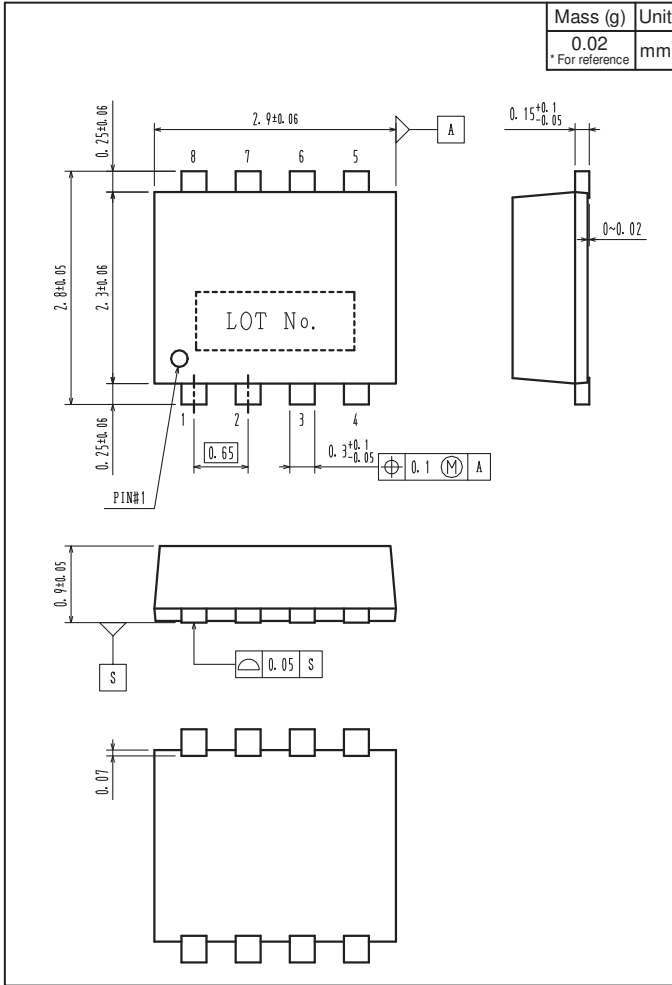


Those with pin 1 index on the feed hole side.....TL

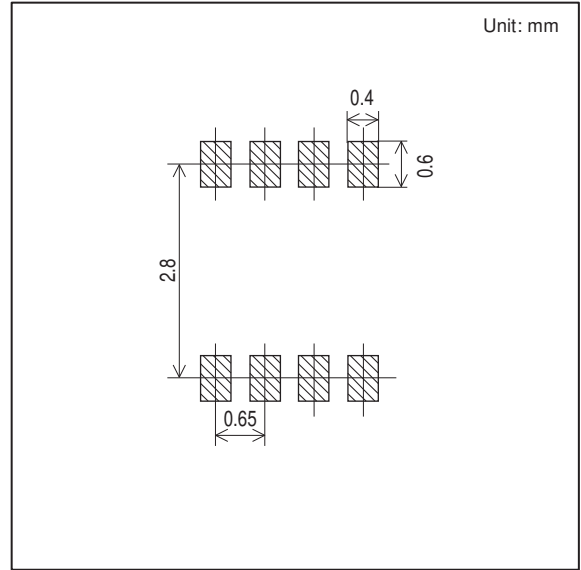
# ECH8652

## Outline Drawing

ECH8652-TL-H



## Land Pattern Example



Note on usage : Since the ECH8652 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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